

# 54F/74F676 16-Bit Serial/Parallel-In, Serial-Out Shift Register

### **General Description**

The 'F676 contains 16 flip-flops with provision for synchronous parallel or serial entry and serial output. When the Mode (M) input is HIGH, information present on the parallel data ( $P_0-P_{15}$ ) inputs is entered on the falling edge of the Clock Pulse ( $\overline{CP}$ ) input signal. When M is LOW, data is shifted out of the most significant bit position while information present on the Serial (SI) input shifts into the least significant bit position. A HIGH signal on the Chip Select ( $\overline{CS}$ ) input prevents both parallel and serial operations.

#### **Features**

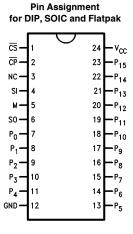
- 16-bit parallel-to-serial conversion
- 16-bit serial-in, serial-out
- Chip select control
- Slim 24 lead 300 mil package

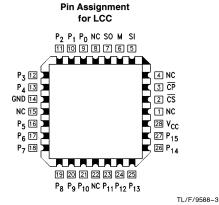
Commercial	Military	Package Number	Package Description		
74F676PC		N24A	24-Lead (0.600" Wide) Molded Dual-In-Line		
74F676SPC		N24C	24-Lead (0.300" Wide) Molded Dual-In-Line		
	54F676DM (Note 2)	J24A	24-Lead (0.600" Wide) Ceramic Dual-In-Line		
	54F676SDM (Note 2)	J24F	24-Lead (0.300" Wide) Ceramic Dual-In-Line		
74F676SC (Note 1)		M24B	24-Lead (0.300" Wide) Molded Small Outline, JEDEC		
	54F676FM (Note 2)	W24C	24-Lead Cerpack		
	54F676LM (Note 2)	E28A	24-Lead Ceramic Leadless Chip Carrier, Type C		

Note 1: Devices also available in 13" reel. Use suffix = SCX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

#### **Connection Diagrams**

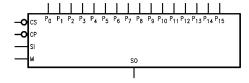




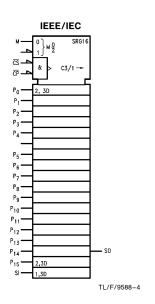
TL/F/9588-2

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## **Logic Symbols**



TL/F/9588-1



# **Unit Loading/Fan Out**

		54F/74F			
Pin Names	Description	U.L. HIGH/LOW	Input I <sub>IH</sub> /I <sub>IL</sub> Output I <sub>OH</sub> /I <sub>OL</sub>		
P <sub>0</sub> -P <sub>15</sub>	Parallel Data Inputs	1.0/1.0	20 μA/-0.6 mA		
P <sub>0</sub> -P <sub>15</sub>	Chip Select Input (Active LOW)	1.0/1.0	20 μA/ – 0.6 mA		
CP	Clock Pulse Input (Active LOW)	1.0/1.0	$20 \mu\text{A}/-0.6 \text{mA}$		
M	Mode Select Input	1.0/1.0	20 μA/ – 0.6 mA		
SI	Serial Data Input	1.0/1.0	$20 \mu\text{A}/-0.6 \text{mA}$		
SO	Serial Output	50/33.3	-1 mA/20 mA		

## **Functional Description**

The 16-bit shift register operates in one of three modes, as indicated in the Shift Register Operations Table.

**HOLD**—a HIGH signal on the Chip Select  $(\overline{CS})$  input prevents clocking, and data is stored in the sixteen registers.

**Shift/Serial Load**—data present on the SI pin shifts into the register on the falling edge of  $\overline{\text{CP}}$ . Data enters the  $Q_0$  position and shifts toward  $Q_{15}$  on successive clocks, finally appearing on the SO pin.

**Parallel Load**—data present on  $P_0-P_{15}$  are entered into the register on the falling edge of  $\overline{CP}$ . The SO output represents the  $Q_{15}$  register output.

To prevent false clocking,  $\overline{\text{CP}}$  must be LOW during a LOW-to-HIGH transition of  $\overline{\text{CS}}.$ 

#### **Shift Register Operations Table**

С	ontrol Inp	Operating Mode				
CS	M	CP	Operating mode			
Н	Х	Х	Hold			
L	L	$\overline{}$	Shift/Serial Load			
L	Н	$\overline{}$	Parallel Load			

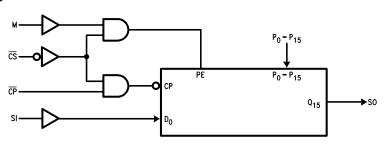
H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

= HIGH-to-LOW Transition

## **Block Diagram**



TL/F/9588-5

#### **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{lll} \mbox{Storage Temperature} & -65^{\circ}\mbox{C to} + 150^{\circ}\mbox{C} \\ \mbox{Ambient Temperature under Bias} & -55^{\circ}\mbox{C to} + 125^{\circ}\mbox{C} \\ \mbox{Junction Temperature under Bias} & -55^{\circ}\mbox{C to} + 175^{\circ}\mbox{C} \\ \mbox{Plastic} & -55^{\circ}\mbox{C to} + 150^{\circ}\mbox{C} \\ \end{array}$ 

V<sub>CC</sub> Pin Potential to

Ground Pin -0.5V to +7.0V Input Voltage (Note 2) -0.5V to +7.0V Input Current (Note 2) -30 mA to +5.0 mA

Voltage Applied to Output in HIGH State (with  $V_{CC} = 0V$ )

 $\begin{array}{ll} \text{Standard Output} & -0.5 \text{V to V}_{CC} \\ \text{TRI-STATE} \tiny{\textcircled{\tiny{\$}}} \text{ Output} & -0.5 \text{V to } +5.5 \text{V} \end{array}$ 

Current Applied to Output

in LOW State (Max) twice the rated I<sub>OL</sub> (mA)

**Note 1:** Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

# Recommended Operating Conditions

Free Air Ambient Temperature

Supply Voltage

Military + 4.5V to + 5.5V Commercial + 4.5V to + 5.5V

## **DC Electrical Characteristics**

Symbol	Parameter		54F/74F			Units	v <sub>cc</sub>	Conditions	
Symbol			Min	Тур	Max	Oilles	VCC	Conditions	
$V_{IH}$	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal	
$V_{IL}$	Input LOW Voltage				0.8	V		Recognized as a LOW Signal	
$V_{CD}$	Input Clamp Diode Vo	oltage			-1.2	V	Min	$I_{\text{IN}} = -18 \text{ mA}$	
V <sub>OH</sub>	Output HIGH Voltage	54F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub> 74F 5% V <sub>CC</sub>	2.5 2.5 2.7			V	Min	$I_{OH} = -1 \text{ mA}$ $I_{OH} = -1 \text{ mA}$ $I_{OH} = -1 \text{ mA}$	
V <sub>OL</sub>	Output LOW Voltage	54F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub>			0.5 0.5	V	Min	$I_{OL} = 20 \text{ mA}$ $I_{OL} = 20 \text{ mA}$	
I <sub>IH</sub>	Input HIGH Current	54F 74F			20.0 5.0	μΑ	Max	$V_{IN} = 2.7V$	
I <sub>BVI</sub>	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	V <sub>IN</sub> = 7.0V	
I <sub>CEX</sub>	Output HIGH Leakage Current	54F 74F			250 50	μΑ	Max	$V_{OUT} = V_{CC}$	
$V_{ID}$	Input Leakage Test	74F	4.75			٧	0.0	$I_{\text{ID}} = 1.9  \mu\text{A},$ All Other Pins Grounded	
I <sub>OD</sub>	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	V <sub>IOD</sub> = 150 mV, All Other Pins Grounded	
I <sub>IL</sub>	Input LOW Current				-0.6	mA	Max	V <sub>IN</sub> = 0.5V	
I <sub>OS</sub>	Output Short-Circuit Current		-60		<b>-150</b>	mA	Max	V <sub>OUT</sub> = 0V	
Icc	Power Supply Curren	t			72	mA	Max		

# **AC Electrical Characteristics**

	Parameter				5	4F	74F		
Symbol					T <sub>A</sub> , V <sub>CC</sub> = Mil C <sub>L</sub> = 50 pF		T <sub>A</sub> , V <sub>CC</sub> = Com C <sub>L</sub> = 50 pF		Units
		Min	Тур	Max	Min	Max	Min	Max	
f <sub>max</sub>	Maximum Clock Frequency	100	110		45		90		MHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay <del>CP</del> to SO	4.5 5.0	9.0 9.0	11.0 12.5	4.5 5.0	17.0 14.5	4.5 5.0	12.0 13.5	ns

# **AC Operating Requirements**

Symbol		$74F$ $T_A = +25^{\circ}C$ $V_{CC} = +5.0V$		54	F	74F		
	Parameter			T <sub>A</sub> , V <sub>CC</sub> = Mil		T <sub>A</sub> , V <sub>CC</sub> = Com		Units
		Min	Max	Min	Max	Min	Max	
t <sub>S</sub> (H) t <sub>S</sub> (L)	Setup Time, HIGH or LOW SI to $\overline{\text{CP}}$	4.0 4.0		4.0 4.0		4.0 4.0		ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold Time, HIGH or LOW SI to CP	4.0 4.0		4.0 4.0		4.0 4.0		113
t <sub>S</sub> (H) t <sub>S</sub> (L)	Setup Time, HIGH or LOW P <sub>n</sub> to CP	3.0 3.0		3.0 3.0		3.0 3.0		ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold Time, HIGH or LOW P <sub>n</sub> to CP	4.0 4.0		4.0 4.0		4.0 4.0		113
t <sub>s</sub> (H) t <sub>s</sub> (L)	Setup Time, HIGH or LOW M to CP	8.0 8.0		8.0 8.0		8.0 8.0		ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold Time, HIGH or LOW M to CP	2.0 2.0		2.0 2.0		2.0 2.0		113
t <sub>s</sub> (L)	Setup Time, LOW CS to CP	10.0		12.0		10.0		ns
t <sub>h</sub> (H)	Hold Time, HIGH CS to CP	10.0		10.0		10.0		115
t <sub>w</sub> (H) t <sub>w</sub> (L)	CP Pulse Width HIGH or LOW	4.0 6.0		5.0 9.0		4.0 6.0		ns

## **Ordering Information**

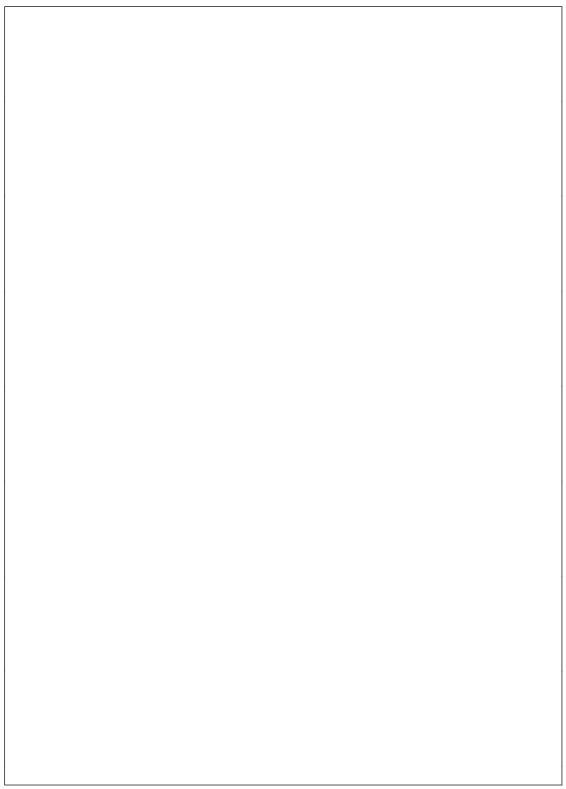
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

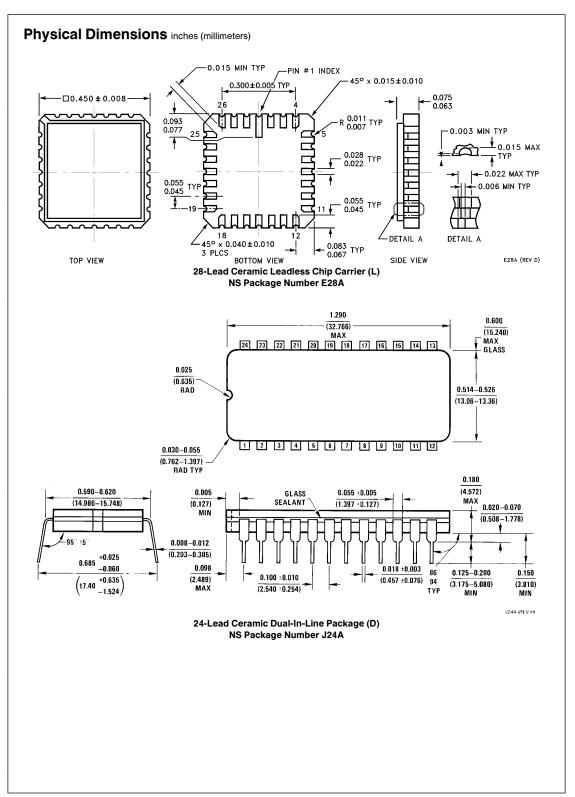
<u>74F 676 Ş Ç</u> - Special Variations QB = Military grade device with Temperature Range Family 74F = Commercial 54F = Military environmental and burn-in processing Device Type Temperature Range C = Commercial (0°C to +70°C) Package Code -P = Plastic DIP SP = Slim Plastic DIP  $M = Military (-55^{\circ}C to + 125^{\circ}C)$ 

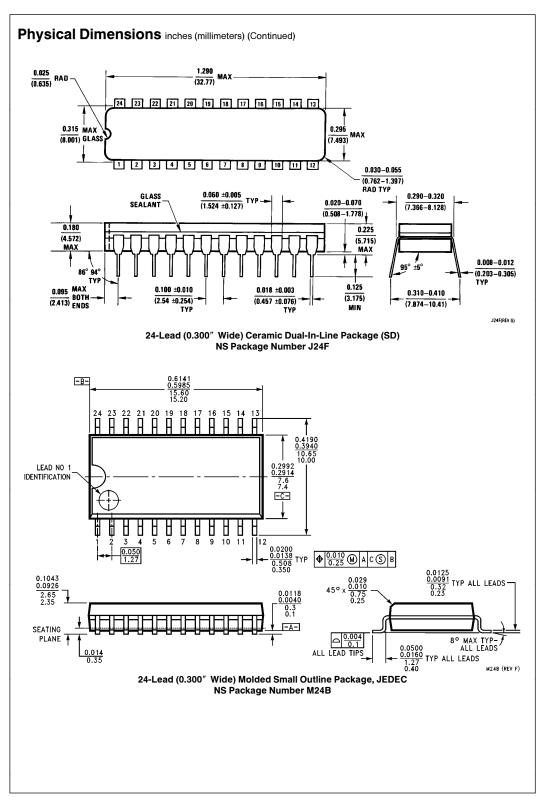
SD = Slim Ceramic DIP F = Flatpak

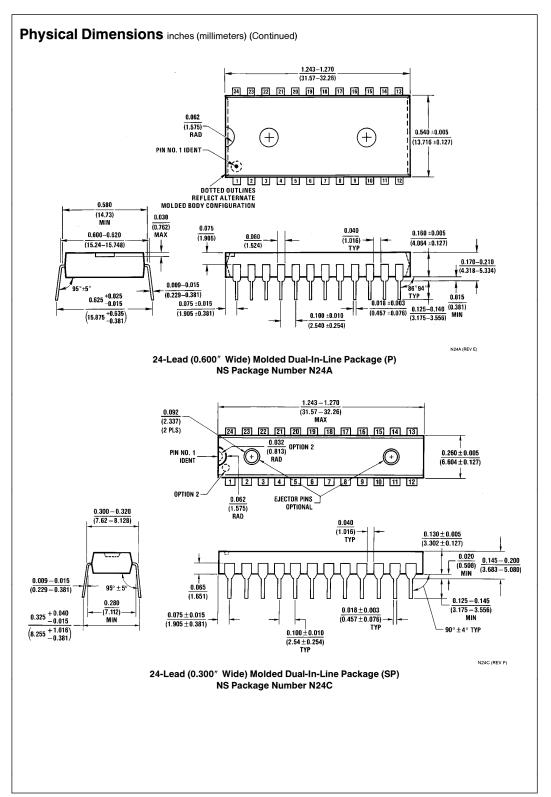
D = Ceramic DIP

Leadless Chip Carrier (LCC) Small Outline SOIC JEDEC L =

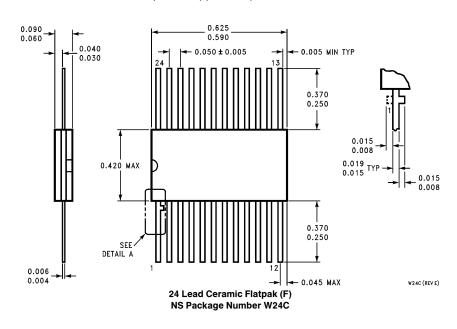








# Physical Dimensions inches (millimeters) (Continued)



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